

Vishay Siliconix

N-Channel 40-V (D-S) 175 °C MOSFET

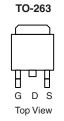
PRODUCT SUMMARY				
V _{(BR)DSS} (V)	r _{DS(on)} (Ω)	I _D (A)	Q _g (Typ.)	
40	0.0053 at V _{GS} = 10 V	110	95	

FEATURES

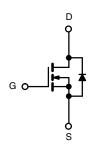
- TrenchFET[®] Power MOSFET
- 175 °C Junction Temperature



• High Threshold Voltage at High Temperature



Ordering Information: SUM110N04-05H-E3 (Lead (Pb)-free)



N-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS $T_C = 2$	25 °C, unless other	wise noted			
Parameter		Symbol	Limit	Unit	
Drain-Source Voltage		V _{DS}	40	v	
Gate-Source Voltage		V _{GS}	20	v	
Continuous Drain Current (T ₁ = 175 °C)	T _C = 25 °C	L	110		
$Continuous Drain Current (1_j = 175 C)$	T _C = 125 °C	D D	70	•	
Pulsed Drain Current		I _{DM}	300	- A	
Avalanche Current		I _{AR}	50		
Repetitive Avalanche Energy ^a	L = 0.1 mH	E _{AR}	125	mJ	
	T _C = 25 °C	Б	150 ^b	14/	
Maximum Power Dissipation ^a	T _A = 25 °C ^c	P _D –	3.75	W	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 175	°C	

THERMAL RESISTANCE RATINGS				
Parameter		Symbol	Limit	Unit
Junction-to-Ambient	PCB Mount ^c	R _{thJA}	40	°C/W
Junction-to-Case		R _{thJC}	1	0/11

Notes:

a. Duty cycle \leq 1 %.

b. See SOA curve for voltage derating.

c. When Mounted on 1" square PCB (FR-4 material).

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Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static							
Drain-Source Breakdown Voltage	V _{(BR)DSS}	$V_{DS} = 0 \text{ V}, \text{ I}_{D} = 250 \mu\text{A}$	40			V	
Gate-Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_D = 250 \ \mu A$	3.4	3.8	5.0	V	
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 V, V_{GS} = \pm 20 V$			± 100	nA	
Zero Gate Voltage Drain Current		$V_{DS} = 40 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$			1		
	I _{DSS}	V_{DS} = 40 V, V_{GS} = 0 V, T_{J} = 125 °C			50	μΑ	
		$V_{DS} = 40 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 175 ^{\circ}\text{C}$			250		
On-State Drain Current ^a	I _{D(on)}	V _{DS} = 5 V, V _{GS} = 10 V	120			А	
Drain-Source On-State Resistance ^a		V _{GS} = 10 V, I _D = 30 A		0.0044	0.0053		
	r _{DS(on)}	V_{GS} = 10 V, I _D = 30 A, T _J = 125 °C			0.008	Ω	
		V_{GS} = 10 V, I_{D} = 30 A, T_{J} = 175 °C			0.0106		
Forward Transconductance ^a	9 _{fs}	V _{DS} = 15 V, I _D = 15 A	20	50		S	
Dynamic ^b	1						
Input Capacitance	C _{iss}	V _{GS} = 0 V, V _{DS} = 25 V, f = 1 MHz		6700		pF	
Output Capacitance	C _{oss}			600			
Reverse Transfer Capacitance	C _{rss}			320			
Total Gate Charge ^c	Qg			95		nC	
Gate-Source Charge ^c	Q _{gs}	$V_{DS} = 20 \text{ V}, \text{ V}_{GS} = 10 \text{ V}, \text{ I}_{D} = 50 \text{ A}$		37			
Gate-Drain Charge ^c	Q _{gd}			21			
Gate Resistance	Rg	f = 1.0 MHz		1.7		Ω	
Turn-On Delay Time ^c	t _{d(on)}			20	30	- ns	
Rise Time ^c	t _r	$V_{DD} = 20 \text{ V, } \text{R}_{\text{L}} = 0.4 \Omega$ $\text{I}_{\text{D}} \cong 50 \text{ A}, \text{ V}_{\text{GEN}} = 10 \text{ V, } \text{R}_{\text{g}} = 2.5 \Omega$		95	145		
Turn-Off Delay Time ^c	t _{d(off)}			50	75		
Fall Time ^c	t _f			12	20		
Source-Drain Diode Ratings and Cha	racteristics T	_C = 25 °C ^b	1	1	I I		
Continuous Current	ا _S				100		
Pulsed Current	I _{SM}				300	A	
Forward Voltage ^a	V _{SD}	I _F = 30 A, V _{GS} = 0 V		0.90	1.50	V	
Reverse Recovery Time	t _{rr}	I _F = 30 A, di/dt = 100 A/μs		40	60	ns	

Notes:

a. Pulse test; pulse width \leq 300 $\mu s,$ duty cycle \leq 2 %.

b. Guaranteed by design, not subject to production testing.

c. Independent of operating temperature.

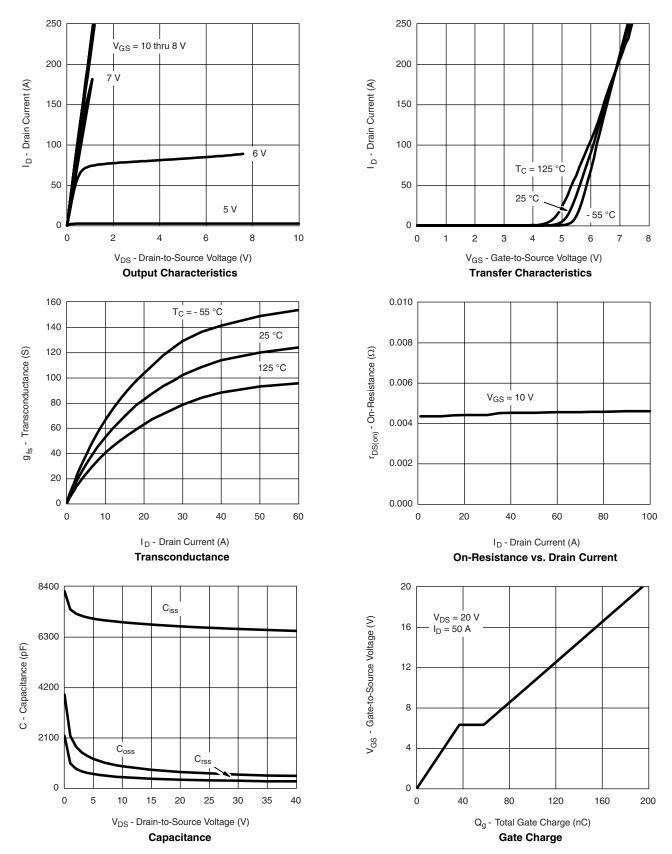
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



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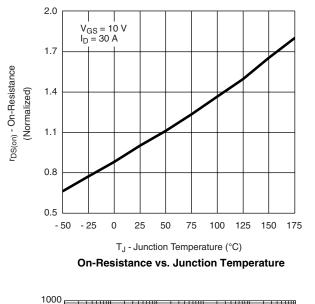
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

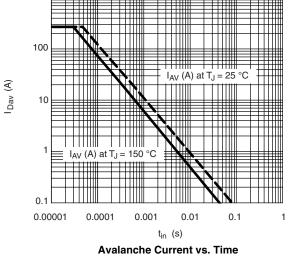


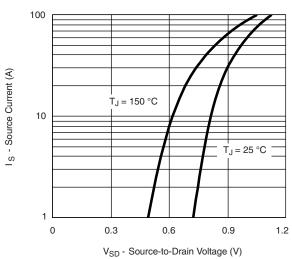
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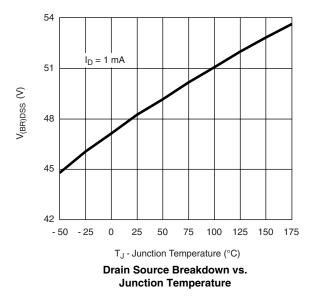
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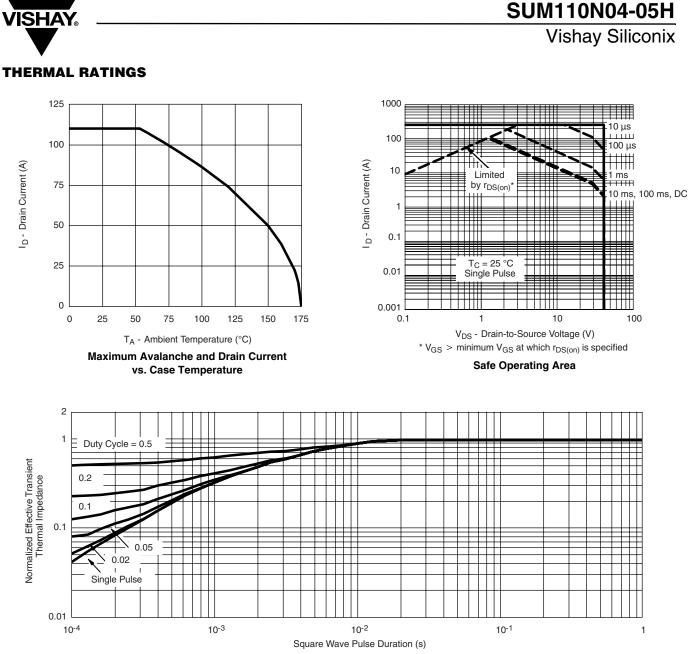




Source-Drain Diode Forward Voltage



4



Normalized Thermal Transient Impedance, Junction-to-Case

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see http://www.vishay.com/ppg?73131.



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